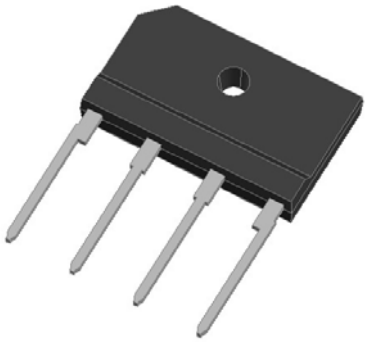
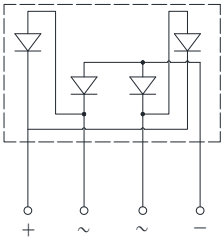
Bridge Rectifiers





Features

- Glass passivated chip junction
- Thin single in-line package
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.

Mechanical Data

- **Package**: 4KBJ
  Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■Maximum Ratings (T_a=25℃ Unless otherwise specified）

PARAMETER		SYMBOL	UNIT	KBJ4A	KBJ4B	KBJ4D	KBJ4G	KBJ4J	KBJ4K	KBJ4M
Device marking code				KBJ4A	KBJ4B	KBJ4D	KBJ4G	KBJ4J	KBJ4K	KBJ4M
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	V	50	100	200	400	600	800	1000
Maximum RMS Voltage		V_{RMS}	V	35	70	140	280	420	560	700
Maximum DC blocking Voltage		V_{DC}	V	50	100	200	400	600	800	1000
Average Rectified Output Current @60Hz sine wave, R-load	With heatsink T_C =125℃	I_O	A	4.0						
	Without heatsink T_a =25℃			2.6						
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25℃		I_{FSM}	A	135						
Current squared time @1ms≤t≤8.3ms, Tj=25℃, rating of per diode		I^2t	A^2S	75.6						
Storage temperature		T_{stg}	℃	-55 ~ +150						
Junction temperature		T_j	℃	-55 ~ +150						
Dielectric strength @ Terminals to case, AC 1 minute		V_{dis}	KV	2						
Mounting torque @Recommend torque：5kg·cm		Tor	kg·cm	8						

■Electrical Characteristics（T_a=25℃ Unless otherwise specified）

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	KBJ4A	KBJ4B	KBJ4D	KBJ4G	KBJ4J	KBJ4K	KBJ4M
Maximum instantaneous forward voltage drop per diode	V_F	V	I_{FM}=2.0A	1.0						
Maximum DC reverse current at rated DC blocking voltage per diode	I_R	μA	T_j =25℃	5						
			T_j =125℃	100						
Typical junction capacitance	Cj	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	38						

■Thermal Characteristics （T_a=25℃ Unless otherwise specified）

PARAMETER		SYMBOL	UNIT	KBJ4A	KBJ4B	KBJ4D	KBJ4G	KBJ4J	KBJ4K	KBJ4M
Thermal Resistance	Between junction and ambient, Without heatsink	$R_{\theta J-A}$	℃/W	20						
	Between junction and case, With heatsink	$R_{\theta J-C}$		3						

Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

■Ordering Information (Example)

PREFERED P/N	PACKAGE CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
KBJ4A ~ KBJ4M	B1	Approximate 3.93	20	1000	2000	Tube

■ Characteristics (Typical)

FIG1:Io-Tc Curve

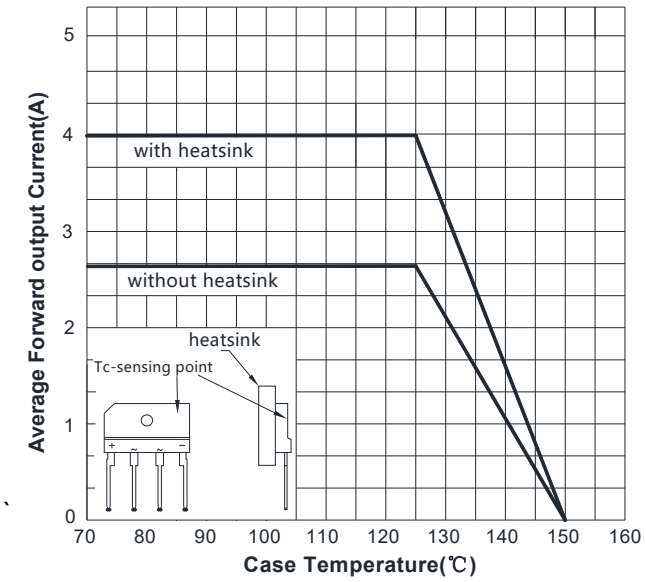


FIG2:Surge Forward Current Capability

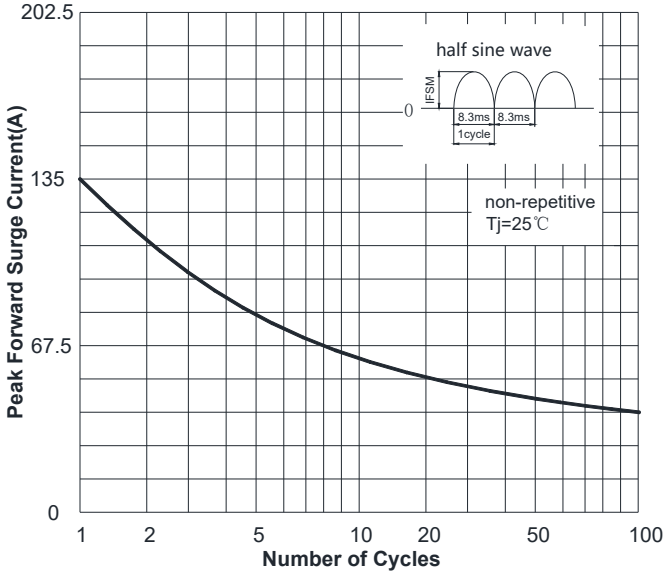


FIG3: Typical Forward Voltage

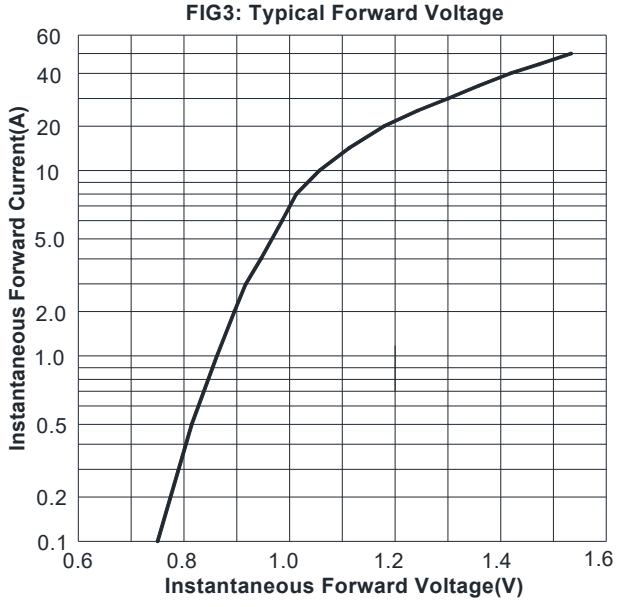
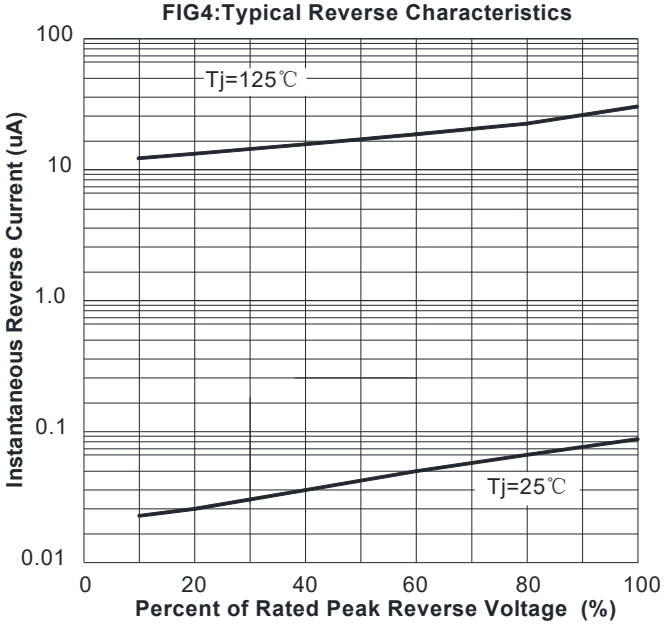
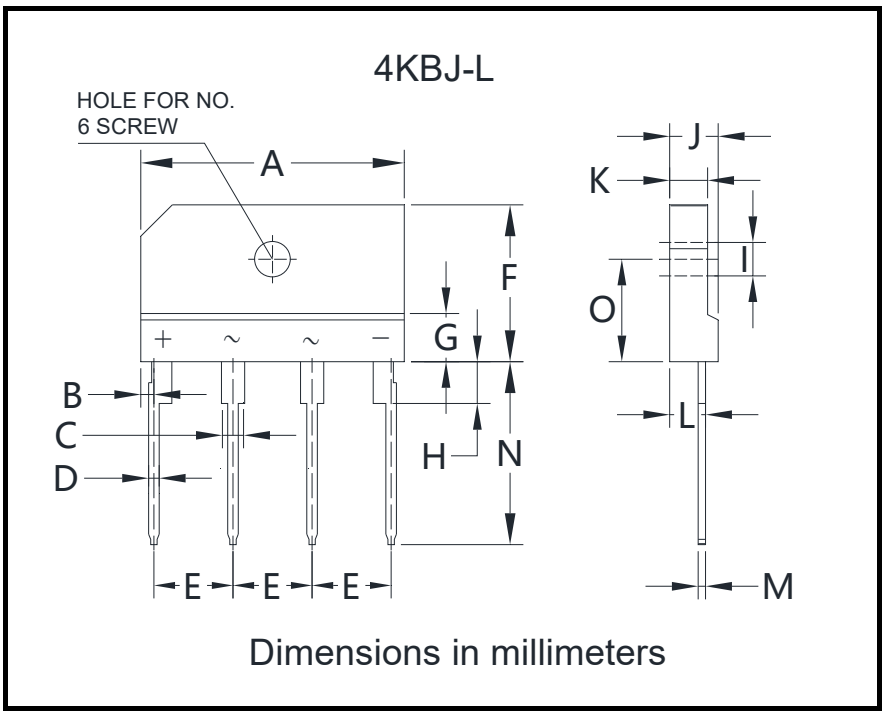


FIG4:Typical Reverse Characteristics



■ Outline Dimensions



4KBJ-L		
Dim	**Min**	**Max**
A	24.7	25.3
B	1.05	1.45
C	1.7	2.1
D	0.9	1.1
E	7.3	7.7
F	14.7	15.3
G	3.8	4.2
H	3.3	3.7
I	3.1	3.4
J	4.4	4.8
K	3.4	3.8
L	2.95	3.25
M	0.35	0.65
N	17.0	18.0
O	9.5	10.1

Notice

All products, product specifications and data are subject to change without notice to improve reliability, function or design or otherwise. Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in STARSEA's terms and conditions of sale for such products, STARSEA assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of STARSEA products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.